Government of Karnataka

Karnataka School Examination and Assessment Board (KSEAB)

Blueprint for Model Question Paper – 2

Subject: II PUC Electronics (40)

Academic Year: 2024-25

| | | | | Rer | nembe | er (35% | ⁄0) | Understand (35%) | | | Apply (20%) | | | нотѕ | | | |
|----|--|------|-------|-----|-------|---------|-------------|------------------|-----|----|-------------|----|-----|------|------------|----|----|
| | Chapters | Hour | Marks | MCQ | SA | LA | LA | MCQ | FIB | SA | LA | LA | MCQ | SA | LA | LA | LA |
| | | | | 1M | 2M | 3M | 5M | 1M | 1M | 2M | 3M | 5M | 1M | 2M | 3 M | 5M | 5M |
| 1 | Field Effect Transistor (FET) | 04 | 04 | 1 | | | | | | | 1 | | | | | | |
| 2 | Transistor Biasing | 03 | 03 | | 1 | | | 1 | | | | | | | | | |
| 3 | Transistor Amplifiers | 14 | 12 | 1 | | | | | 1* | | | 1E | | | | | 1N |
| 4 | Feedback in Amplifiers | 06 | 06 | | | 1 | | 1 | | | | | | 1N | | | |
| 5 | Operational Amplifiers | 15 | 13 | 1 | | | 1E | 1 | 1* | | | | | | | 1N | |
| 6 | Oscillators | 08 | 07 | 1 | | | | | 1* | | 1 | | | 1N | | | |
| 7 | Wireless Communication | 04 | 04 | | | 1 | | 1 | | | | | | | | | |
| 8 | Modulation and Demodulation | 15 | 12 | 1 | | 1 | | | 1* | 1 | | | | | | | 1N |
| 9 | Power Electronics and its applications | 08 | 06 | 1 | | | | | | 1 | | | | | 1N | | |
| 10 | Digital Electronics | 18 | 18 | 1 | 1 | | 1E | | 1* | | | | 1 | | 1N | 1N | |
| 11 | Microcontroller | 10 | 08 | 1 | 1 | | | | | | | 1E | | | | | |
| 12 | C Programming | 09 | 06 | 1 | | | | | | | | 1E | | | | | |
| 13 | Modern Communication Systems | 06 | 06 | | | 1 | | 1 | | 1 | | | | | | | |
| | Total | 120 | 105 | 9 | 6 | 12 | 10 | 5 | 5* | 06 | 06 | 15 | 01 | 04 | 06 | 10 | 10 |
| | | | | | 37 | 7 | | | | 37 | | | | 2: | 1 | | 10 |

* – Fill in the blank,

| | on Paper F PUC Electr | | |
|------------------------------------|--------------------------|---|--------------------------|
| Parts | Marks per Question | Total Questions given including choices | Questions to be answered |
| Part A – I (MCQ) | 1 | $15Q \times 1M = 15$ | $15Q \times 1M = 15$ |
| Part A – II (Fill in the Blanks) | 1 | $5Q \times 1M = 05$ | $5Q \times 1M = 05$ |
| Part B - III | 2 | $8Q \times 2M = 16$ | $5Q \times 2M = 10$ |
| Part C - IV | 3 | $8Q \times 3M = 24$ | $5Q \times 3M = 15$ |
| Part D - V Section I (Essay Type) | 5 | $5Q \times 5M = 25$ | $3Q \times 5M = 15$ |
| Part D - VI Section II (Numerical) | 5 | $4Q \times 5M = 20$ | $2Q \times 5M = 10$ |
| | | 105 | 70 |

Guidelines to question paper setters

- Q No. 27 Short answer from microcontroller (meanings of mnemonics to be avoided).
- Q No. 34 Numerical on HWR or FWR for the given rms voltage.
- Q No. 35 Numerical (excluding POS).
- Q No. 37 Working of any one amplifier circuit.
- Q No. 38 Derivation on any one op-amp circuit.
- Q No. 40 ALP program (from the specified programs in the syllabus).
- Q No. 41 C program (from the specified programs in the syllabus).
- Q No. 42 Numerical on transistor re' model (only silicon transistor).

Mention $V_{BE} = 0.7 \text{ V}$ and $r_e' = 26 \text{mV}/\text{I}_E$ in the problem.

- Q No. 43 Numerical on applications of OP-Amp (excluding differentiator and integrator).
- Q No. 44 Numerical on AM.
- Q No. 45 Numerical on four variable K-map (two groups).

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Model Question Paper – 2

| Subject: II PUC Electron | iics (40) | Academic Year: 2024-25 |
|---|--|-------------------------------|
| [Time: 3 Hours] | [Total No. of Questions: 45] | [Max. Marks: 70] |
| Instructions: | | |
| For PART-A que evaluation. Part – D consis | estions, only the first written answers | s will be considered for |
| | f essay type questions and Section | I is of problems |
| | | |
| _ | and truth tables must be drawn wh | nerever necessary. |
| 5. For questions h | ems with necessary formulae. having diagrams, alternate questions in separate section for visually chall | - |
| | PART A | |
| I. Select the correct answ | ver from the choices given: | 15 x 1 = 15 |
| 1. Drain characteristics of | of JFET in Ohmic region is | |
| a) nonlinear | b) linear c) exponentia | al d) constant |
| 2. The most commonly u | used biasing circuit for the stable ope | erating point is |
| a) Fixed bias | b) Collector to base f | eedback bias |
| c) Emitter feedback b | ias d) Voltage divider bia | as |
| If A_m is the voltage gain the voltage gain at cu | in of transistor amplifier at mid frequ itoff frequencies? | uency band, then what will be |
| a) A _m /2 | b) A _m /v2 c) 2A _m | d) √2A _m |
| 4. Negative feedback is u | used in | |
| a) Oscillator | b) Amplifier c) Digital Circu | uit d) Power Devices |
| 5. Phase difference betw | veen the input and output of op-amp | o inverting amplifier is |
| a) 0 ⁰ | b) 90 ⁰ c) 180 ⁰ | d) 270 ⁰ |
| 6. What is the output of | op-amp integrator circuit if sine way | ve is given to its input? |
| a) Sine wave | b) Square wave | |
| c) Cosine wave | d) Triangular wave | |
| 7. Condition for sustaine | | |
| | b) $ A\beta = 1$ c) $ A\beta > 1$ | d) Aβ < 1 |
| 8. Ground waves are also | | |
| a) Surface waves c) Sky wave | b) Space wavesd) Line of sight waves | s |
| CJ SKY WAVE | | 5 |

| 9. The maximum tran | smission efficiency | in AM wave | e is | |
|---|--|---|--|---|
| a) 25% | b) 33.33% | c) 66. | .66% | d) 100% |
| 10. A thyristor is a | | | | |
| a) Controlled devic | | ntrolled dev | | |
| c) Passive device | | e of the abov | е | |
| 11. Excess-3 code of (1 | | | -) 4000000 | |
| a) 00011000 12. A full adder adds | b))0001 | 11110 | c) 1000000 | 1 d) 01001011 |
| a) Two input bits | h) Three | input bits | | |
| c) Four input bits | | nput bytes | | |
| 13. 8051 microcontrol | | | | |
| a) 8 bit controller | b | o) 16 bit cont | roller | |
| c) 32 bit controlle | r d | d) 64 bit con | troller | |
| 14. What is the meani | ng of the C operato | or && (doubl | le ampersand |) |
| a) Bitwise AND | b | o) Bitwise OR | ł | |
| c) Logical AND | | d) Logical OR | R | |
| 15. Expansion of CDM | | | | |
| a) Code Division M | | | l Division Mo | |
| c) Code Division M | | - | l Division Mu | - |
| II. Fill in the blanks by o | choosing appropriate | e answer fror | n the bracket: | 5 X I = 5 |
| | | | | |
| | | nitt trigger | d) modulati | on index e) arithmetic |
| f) high frequency |] | | d) modulati | on index e) arithmetic |
| f) high frequency16.CB amplifier is suita |] able forapp | lications | - | on index e) arithmetic |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete |] able forapp ctor is an application | lications on of | - | on index e) arithmetic |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback |] able forapp ctor is an application is used in Colpitts of | lications on of oscillator. | | |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of |] able forapp ctor is an application is used in Colpitts of amplitude of signa | lications on of oscillator. | | |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback |] able forapp ctor is an application is used in Colpitts of amplitude of signa | lications on of oscillator. | | |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of |] able forapp ctor is an application is used in Colpitts of amplitude of signa | lications on of oscillator. I to amplituc | | s called |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B | lications on of oscillator. I to amplituc | | |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a tra | lications on of oscillator. I to amplituc | le of carrier is | s called 5 x 2 = 10 |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka 22. An amplifier has Zo |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a tra b = 5 kΩ, voltage ga | lications on of oscillator. I to amplituc ansistor. in A = 100 a | le of carrier is | s called 5 x 2 = 10 |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka 22. An amplifier has Zo impedance of the formation |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a tra b = 5 kΩ, voltage ga feedback amplifier | lications on of oscillator. I to amplituc ansistor. in A = 100 a | de of carrier is nd $\beta = 0.02$. | 5 called 5 x 2 = 10 Find the output |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka 22. An amplifier has Zo impedance of the feedback 23. Determine frequent |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a transfer $p = 5 k\Omega$, voltage gas feedback amplifier here of the tank circ | lications on of oscillator. I to amplituc ansistor. in A = 100 a uit. Given L | de of carrier is nd $\beta = 0.02$. | 5 called 5 x 2 = 10 Find the output |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka 22. An amplifier has Zo impedance of the feedback 23. Determine frequent 24. Write the circuit dia |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a tra- $p = 5 k\Omega$, voltage ga feedback amplifier noy of the tank circ iagram of diode de | lications on of oscillator. I to amplituc ansistor. in A = 100 a uit. Given L tector. | de of carrier is nd $\beta = 0.02$. = 10 mH and | s called 5 x 2 = 10 Find the output C = 1 μ F. |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka 22. An amplifier has Zo impedance of the feedback 23. Determine frequent 24. Write the circuit dit 25. Sketch electric field |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a tra- b = 5 kΩ, voltage ga feedback amplifier incy of the tank circ iagram of diode de d strength of punct | lications on of oscillator. I to amplituc ansistor. in A = 100 a uit. Given L tector. | de of carrier is nd $\beta = 0.02$. = 10 mH and | s called 5 x 2 = 10 Find the output C = 1 μ F. |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka 22. An amplifier has Zo impedance of the feedback 23. Determine frequent 24. Write the circuit dit 25. Sketch electric field 26. Draw the pin diagree |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a tra $g = 5 k\Omega$, voltage ga feedback amplifier hecy of the tank circ iagram of diode de d strength of punch am of IC 7402. | lications on of oscillator. I to amplituc ansistor. in A = 100 a uit. Given L tector. h through typ | de of carrier is nd $\beta = 0.02$. = 10 mH and pe power dio | s called $5 \times 2 = 10$ Find the output $C = 1 \mu F.$ de. |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka 22. An amplifier has Zoo impedance of the feedback 23. Determine frequent 24. Write the circuit dit 25. Sketch electric field 26. Draw the pin diagroup 27. Mention the memory |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a tra $\sigma = 5 k\Omega$, voltage ga feedback amplifier incy of the tank circ iagram of diode de d strength of punch am of IC 7402. ory capacity of inte | lications on of oscillator. I to amplituc ansistor. in A = 100 a uit. Given L tector. h through typ ernal RAM ar | md $\beta = 0.02$. = 10 mH and pe power dio | s called $5 \times 2 = 10$ Find the output $C = 1 \mu F.$ de. |
| f) high frequency 16.CB amplifier is suita 17. Zero crossing dete 18 feedback 19. In AM the ratio of 20. A half adder is III. Answer any FIVE of 21. Mention two leaka 22. An amplifier has Zo impedance of the feedback 23. Determine frequent 24. Write the circuit dit 25. Sketch electric field 26. Draw the pin diagree |] able forapp ctor is an application is used in Colpitts of amplitude of signa circuit. PART B questions: age currents in a tra $\sigma = 5 k\Omega$, voltage ga feedback amplifier incy of the tank circ iagram of diode de d strength of punch am of IC 7402. ory capacity of inte | lications on of oscillator. I to amplituc ansistor. in A = 100 a uit. Given L tector. h through typ ernal RAM ar | md $\beta = 0.02$. = 10 mH and pe power dio | s called $5 \times 2 = 10$ Find the output $C = 1 \mu F.$ de. |

IV. Answer any FIVE questions:

- 29. Explain the construction of n channel JFET.
- 30. Derive an expression for voltage gain of negative feedback amplifier.
- 31. Draw the circuit diagram of Hartley oscillator. Write the expression for the feedback ratio β .
- 32. Write a short note on ionosphere.
- 33. Sketch modulating signal, carrier wave and modulated wave of FM.
- 34. Determine V_{dc} and I_{dc} of SCR HWR. Given firing angle is 60⁰ and rms voltage of ac input to the rectifier is 230 V and load is 10 Ω .
- 35. Convert Y(A, B, C) = $AC + \overline{B}$ into canonical SOP form.
- 36. Write any three uses of satellites.

PART D (Section I)

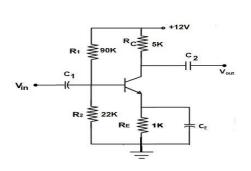
V. Answer any THREE questions:

- 37. Explain the working of a CE amplifier.
- 38. Derive an expression for the output of op-amp subtractor circuit.
- 39. Explain the working of a clocked RS Flip-Flop using NAND gates. Write its truth table.
- 40. Write ALP for the multiplication of unsigned numbers 35H and 45H. Store lower byte in R0 and higher byte in R1.
- 41. Write a C program to accept three integer numbers and print their sum and average.

PART D (Section II)

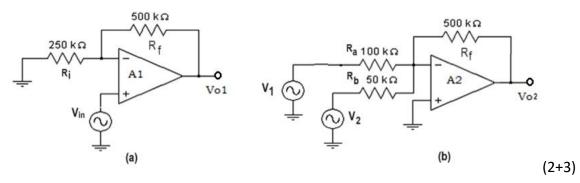
VI. Answer any TWO questions:

42. Calculate the voltage gain, input impedance and output impedance in the circuit shown. Given $\beta = 100$, $V_{BE} = 0.7 V$ and $r_e' = 26 mV/I_E$.



43. Calculate the output voltages of Op-amp circuits shown below.

Given V_{in} = 10 mV, V_1 = 20 mV and V_2 = 30 mV.



44. A sinusoidal carrier voltage V_c = 80 sin2 $\pi \times 10^5$ t is amplitude modulated by a sinusoidal voltage V_m = 32 sin2 $\pi \times 10^3$ t. Write the equation of the AM wave and draw the output frequency spectrum.

3 x 5 = 15

2 x 5 = 10

45. Simplify the Boolean expression

 $Y = \sum m(1, 2, 3, 5, 7, 9, 11, 13) + \sum d(0, 10, 15)$ and then draw the logic diagram for simplified expression using basic gates.

PART-E

(For visually challenged students only)

- 42. In a single stage CE transistor amplifier $R_1 = 90 \text{ k}\Omega$, $R_2 = 22 \text{ k}\Omega$, $R_C = 5 \text{ k}\Omega$, $R_E = 1 \text{ k}\Omega$, $V_{CC} = 12 \text{ V}$, $\beta = 100$, $V_{BE} = 0.7 \text{ V}$ and $r_e' = \frac{26mV}{I_E}$. Calculate the voltage gain, input impedance and output impedance.
- 43. (a) An op-amp noninverting amplifier circuit is given with $R_i = 250 \text{ k}\Omega$, $R_f = 500 \text{ k}\Omega$ and $V_{in} = 10 \text{ mV}$. Determine the output voltage V_{01} .
 - (b) An op-amp inverting adder circuit is given with $R_1 = 100 \text{ k}\Omega$, $R_2 = 50 \text{ k}\Omega$, $R_f = 500 \text{ k}\Omega$ $V_1 = 20 \text{ mV}$ and $V_2 = 30 \text{ mV}$. Determine the output voltage V_{02} .

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